

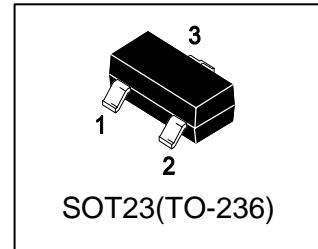
LBSS123LT1G

S-LBSS123LT1G

N-CHANNEL POWER MOSFET

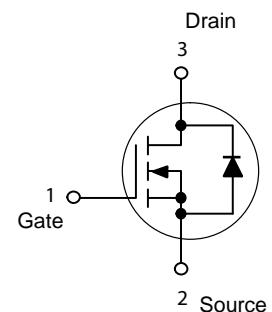
1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.



2. DEVICE MARKING AND ORDERING INFORMATION

| Device | Marking | Shipping |
|-------------|---------|-----------------|
| LBSS123LT1G | SA | 3000/Tape&Reel |
| LBSS123LT3G | SA | 10000/Tape&Reel |



3. MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Limits | Unit |
|---|--------|----------|------|
| Drain–Source Voltage | VDSS | 100 | V |
| Gate–to–Source Voltage – Continuous | VGS | ± 20 | V |
| – Non-repetitive ($t_p \leqslant 50 \mu\text{s}$) | VGSM | ± 40 | |
| Drain Current | ID | 0.17 | A |
| – Continuous (Note 1) | IDM | 0.68 | |
| – Pulsed (Note 2) | | | |

4. THERMAL CHARACTERISTICS

| Parameter | Symbol | Limits | Unit |
|--|-----------------|----------|---------------------------|
| Total Device Dissipation, FR-5 Board (Note 3) @ $T_A = 25^\circ\text{C}$ Derate above 25°C | PD | 225 | mW |
| | | 1.8 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage temperature | T_J, T_{stg} | -55~+150 | $^\circ\text{C}$ |

1. The Power Dissipation of the package may result in a lower continuous drain current.
2. Pulse Width $\leqslant 300 \mu\text{s}$, Duty Cycle $\leqslant 2.0\%$.
3. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

OFF CHARACTERISTICS

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
|--|--------|------|------|---------|------|
| Drain–Source Breakdown Voltage (VGS = 0, ID = 250µA) | VBRDSS | 100 | - | - | V |
| Zero Gate Voltage Drain Current (VGS = 0, VDS = 100 V, Tj=25°C) (VGS = 0, VDS = 100 V, Tj=125°C) | IDSS | - | - | 1 60 | µA |
| Gate–Body Leakage Current (VGS = 20 V, VDS = 0) | IGSS | - | - | 50 | nA |

ON CHARACTERISTICS (Note 4)

| | | | | | |
|--|---------|-----|---|-----|---|
| Gate Threshold Voltage (VDS = VGS, ID = 1.0mA) | VGS(th) | 0.8 | - | 2.0 | V |
| Static Drain–Source On–State Resistance (VGS = 10 V, ID = 100 mA) | RDS(on) | - | 5 | 6 | Ω |
| Forward Transconductance (VGS = 0V, ID = 100 mA) | gfs | 0.8 | - | - | S |

DYNAMIC CHARACTERISTICS

| | | | | | |
|--|------|------|------|------|----|
| Input Capacitance (VDS = 25 V, VGS = 0, f = 1.0 MHz) | Ciss | 15 | 42.7 | 88 | pF |
| Output Capacitance (VDS = 25 V, VGS = 0, f = 1.0 MHz) | Coss | 5 | 14 | 29.5 | pF |
| Reverse Transfer Capacitance (VDS = 25 V, VGS = 0, f = 1.0 MHz) | Crss | 1 | 3 | 6.3 | pF |
| Total Gate Charge (VDS = 10 V, VGS = 10V, ID=0.22A) | Qg | 2.3 | 6.32 | 13.3 | nC |
| Gate-Source Charge (VDS = 10 V, VGS = 10V, ID=0.22A) | Qgs | 0.55 | 1.55 | 3.3 | nC |
| Gate-Drain Charge (VDS = 10 V, VGS = 10V, ID=0.22A) | Qgd | 0.25 | 0.68 | 1.43 | nC |

SWITCHING CHARACTERISTICS (Note 4)

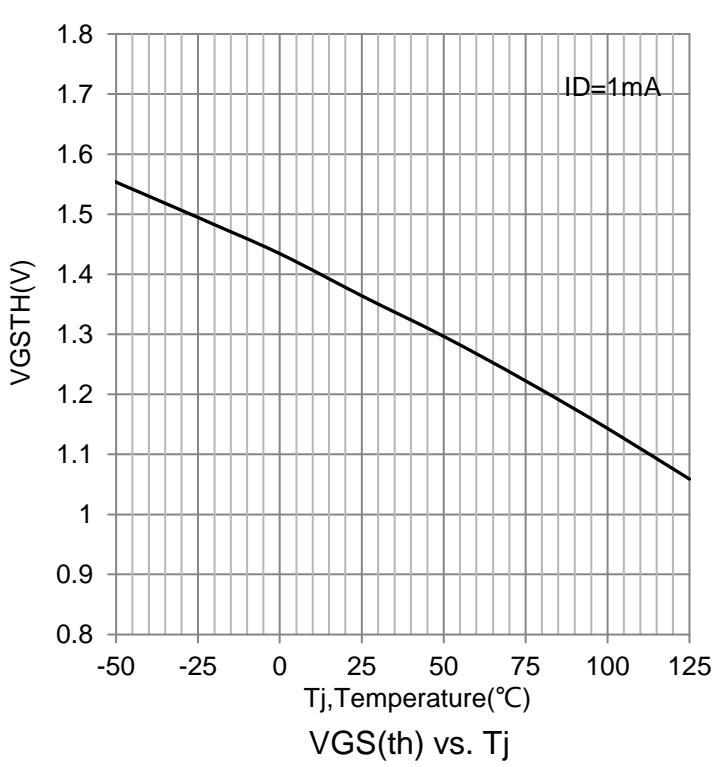
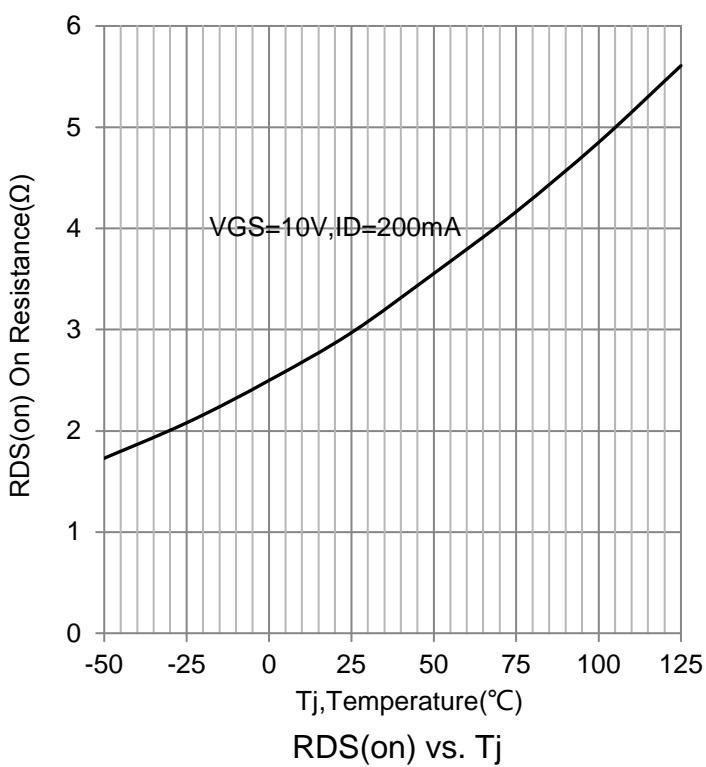
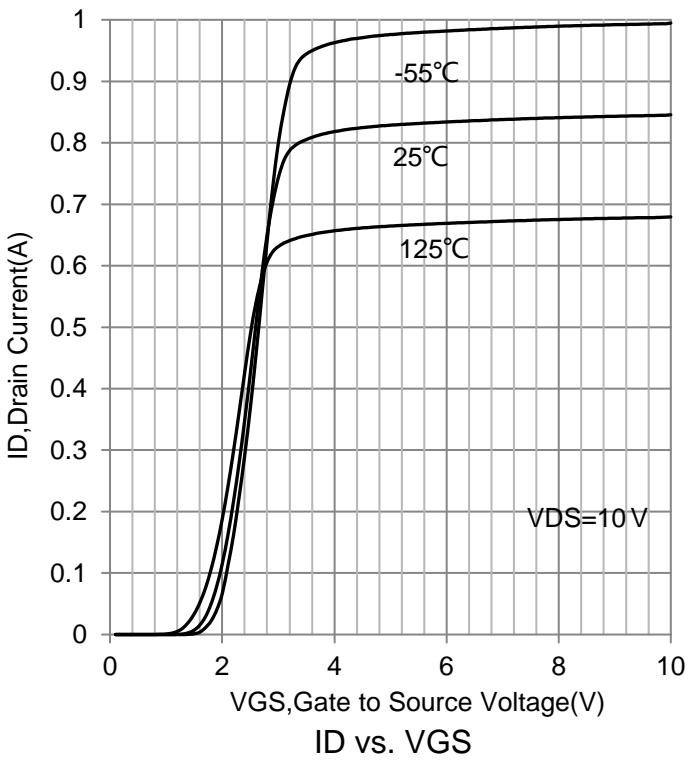
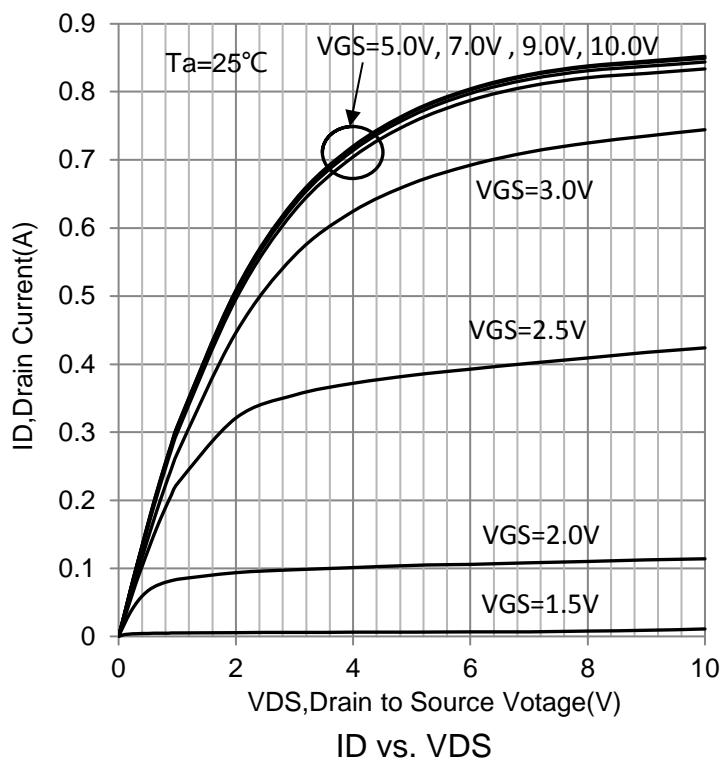
| | | | | | |
|--|---------|---|----|---|----|
| Turn-On Delay Time (VCC = 30 V, IC = 0.28 A, VGS = 10 V, RGS = 50 Ω) | td(on) | - | 20 | - | ns |
| Turn-Off Delay Time | td(off) | - | 40 | - | |

REVERSE DIODE

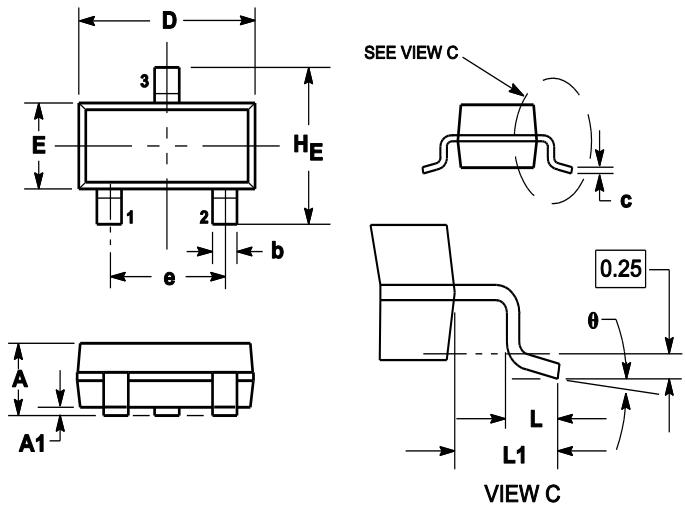
| | | | | | |
|--|-----|---|---|-----|---|
| Diode Forward On–Voltage (ID = 0.34 A, VGS = 0 V) | VSD | - | - | 1.3 | V |
|--|-----|---|---|-----|---|

4. Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%.

6.ELECTRICAL CHARACTERISTICS CURVES



7. OUTLINE AND DIMENSIONS

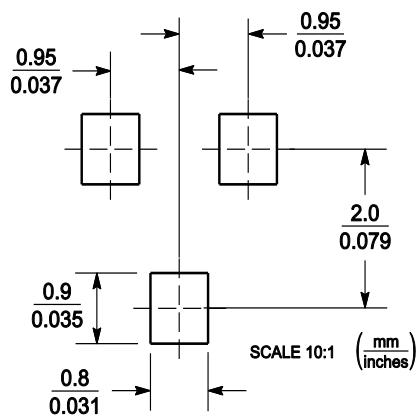


Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

| DIM | MILLIMETERS | | | INCHES | | |
|----------------|-------------|------|------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1 | 1.11 | 0.035 | 0.04 | 0.044 |
| A1 | 0.01 | 0.06 | 0.1 | 0.001 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.5 | 0.015 | 0.018 | 0.02 |
| c | 0.09 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.80 | 2.9 | 3.04 | 0.11 | 0.114 | 0.12 |
| E | 1.20 | 1.3 | 1.4 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.9 | 2.04 | 0.07 | 0.075 | 0.081 |
| L | 0.10 | 0.2 | 0.3 | 0.004 | 0.008 | 0.012 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.029 |
| H _E | 2.10 | 2.4 | 2.64 | 0.083 | 0.094 | 0.104 |
| θ | 0° | --- | 10° | 0° | --- | 10° |

8. SOLDERING FOOTPRINT



DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee.
The curve of test items without electric parameter is used as reference only.
- Before you use our Products for new Project, you are requested to carefully read this document and fully understand its contents. LRC shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any LRC's Products against warning, caution or note contained in this document.
- All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using LRC's Products, please confirm the latest information with a LRC sales representative.